





Lab Works at Grenoble: Overview and Organization

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Outline

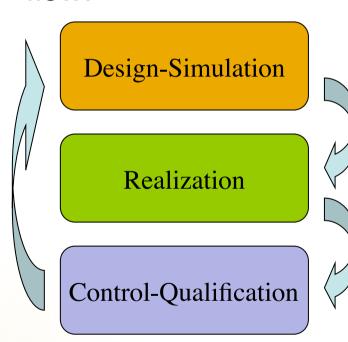
- Objectives
- Organization
 - Study logic
 - Breakdown structure
 - Schedule
 - Where? When?
- Evaluation



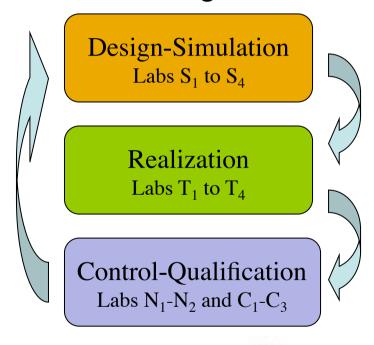


Labs Objectives

 Device manufacturing flow:



Lab-work organization:







Organization

Contacts:

Simulation

S1-S2: Anne Kaminski anne.kaminski@minatec.i

S3-S4: Libor Rufer libor.rufer@imag.fr

Technology

Davide Bucci bucci@minatec.inpg.fl

Characterization

Quentin Rafhay rafhay@minatec.inpg.fr

Nanoworld

Irina Ionica ionica@minatec.inpg.fr

Labs rules:

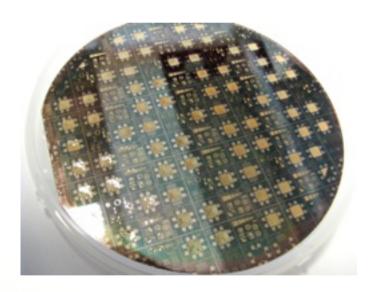
- Attendance to the labs is mandatory!(unjustified absence <=> score reduction)
- Sessions start on time (8 AM or 13 PM)
- Technical staff rules...





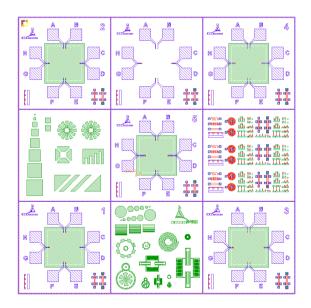
All for one chip, one chip for all

Wafers:



- 4-inches SOI or Si
- CMOS and MEMS devices

Chip layout:

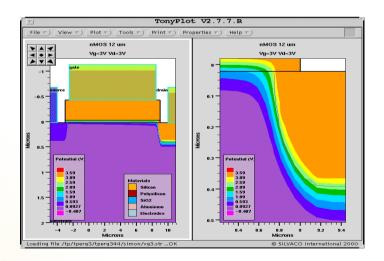




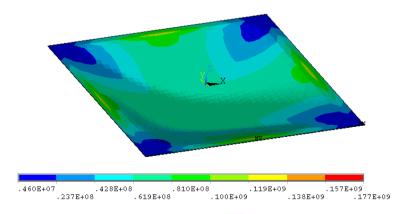


S₁-S₄: Simulation sessions

- S₁: technological sim.
 - Athena software
- S₂: electrical sim.
 - Atlas software



- S₃-S₄: electromechanical simulation
 - ANSYS software
 - Course L. Rufer (MEMS)







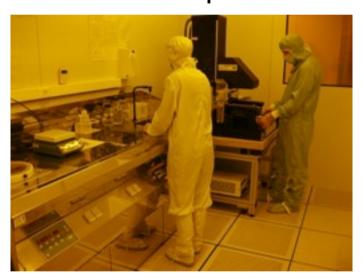
T₁-T₄: Clean-room sessions

- Work in a clean room:
 - Dedicated suits



- Trousers and T-shirt
- Strict respect of the safety procedures
- Bring an USB key

MEMS-CMOS proc. flow:

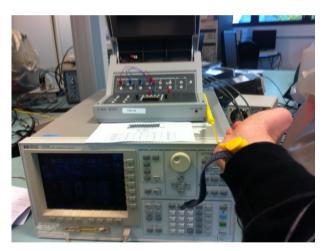


 Double-side photolithography, deep RIE, ion implantation, oxidation, etc...



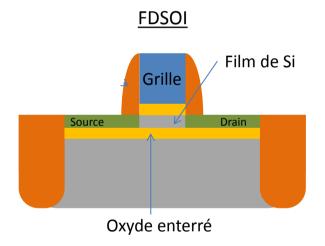
C₁-C₃: Characterization sessions

• C₁₋₂: CMOS caract.



Standard industrial measurements

C₃: FDSOI



Advanced techniques



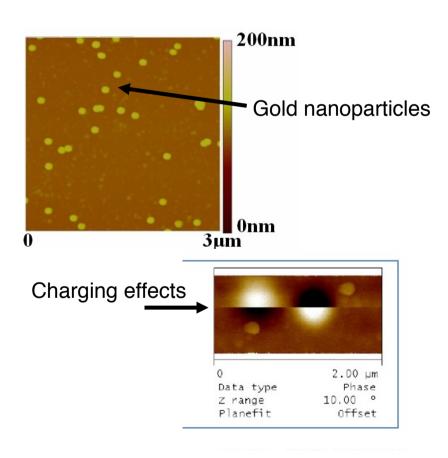


N₁-N₂: Nanoworld sessions

N₁: STM, contact mode AFM

Transistor gate × 5.000 µm/div Graphite atomic structure

N₂: Tapping mode AFM, EFM





Planning

			G1		G2		G3		G4		G5		G6		G7		G8		G9		G10	
Wed	04/02/15	AM	S1	AK	S1		S1		•		-		-				N1	Ш				
Wed	04/02/15	PM	S2	AK	S2		S2					pro	lect				N2	- ii				\Box
Thur	05/02/15	PM	S3	LR	S3		S3						ect			pro	iect			pro	iect	
Wed	11/02/15	AM	T1	DB	T1	QR			S1	AK	S1		S1			_	iect		N1	JCh	000	
Wed	11/02/15	PM	T2	DB	T2	QR		pro	iect			pro	oject			pro	lect		N2	JCh		\Box
Mon	23/02/15	AM	S4	LR	S4		S4		S2	AK	S2		S2			В	01			pro	iect	
Wed	25/02/15	AM	T3	DB	T3	QR	N1	JCh	S3	LR	S3		S3		S1	AK	S1		S1		S1	
Wed	25/02/15	PM	T4	DB	T4	QR	N2	JCh	S4	LR	S4		S4		S2	AK	S2		S2		S2	
Mon	02/03/15	PM	C1	LP	C2			pro	ect						(Comn	nunica	tion	at wor	k		
Wed	04/03/15	AM		pro	lect		T1	DB	T1	MB			N1	LB	S3	LR	S3		S3		S3	
Wed	04/03/15	PM	C2	LP	C1		T2	DB	T2	MB			N2	XM	S4	LR	S4		S4		S4	
Mon	09/03/15	PM			(Comm	unica	tion a	t wor	k							Bio2			pro	lect	
Wed	11/03/15	AM	C3	IBA			T3	DB	T3	MB	N1	LB				pro	ect			pro	ject	
Wed	11/03/15	PM			C3	IBA	T4	DB	T4	MB	N2	XM								pro	iect	
Wed	18/03/15	AM		pro	ect		C1	LP	C2		T1	Aku	T1	AK	N1	LB				Bi	о1	
Wed	18/03/15	PM	project C2 LP C1			T2	Aku	T2	AK	N2	XM				Bio2							
Wed	25/03/15	AM					C3	MB			Т3	Aku	T3	AK		pro	iect				N1	LB
Wed	25/03/15	РМ		pro	lect				C3	MB	T4	Aku	T4	AK	Bio2						N2	XM
Wed	01/04/15	AM	project project					C1	IBA	C2		T1	MB	T1	AK	Com	Communication at wo					
Wed	01/04/15	PM	Communication at work				C2	IBA	C1		T2	MB	T2	AK	project							
Wed	08/04/15	AM	N1	SC				pro	lect		C3	MB			T3		T3	AK	Com			at wo
Wed	08/04/15	PM	N2	XM				pro	ject				C3	MB	T4		T4	AK	Com	munic	ation	at wo
Wed	22/04/15	AM										(Comm	unica	tion a	t wor	k		T1	MB	T1	AK
Wed	22/04/15	PM		(Comm	unica	tion a	t wor	k			pro	ject		C1	IBA	C2		T2	MB	T2	AK
Wed	29/04/15	AM	Communication at work					project project						T3		T3	AK					
Wed	29/04/15	PM						pro	lect				oject		C2		C1		T4		T4	AK
Wed	06/05/15	AM		(Comm	unica	tion a					, pr	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			pro	ject		C1	IBA	C2	
Wed	06/05/15	PM			N1	SC						(Comm	unica	tion a	t wor	k		C1	IBA	C2	
Tues	12/05/15	AM			N2	XM		pro	ject						C3	IBA				pro	ject	
Wed	13/05/15	AM		project N1 SC						project C3 IBA					Communication at wo							
Wed	13/05/15	PM			lect				N2	XM	Communication at work				C3	IBA						
Wed	20/05/15	AM									Communication at work						C3	IBA				
Wed	20/05/15	PM	PM BULATS 14h00-16h00																			

First session: February 4, AM

Tight schedule!





Where and when?

- S₁-S₄: e. hall BCA-I building
- T₁-T₄: e. hall BCA-I building
- N₁-N₂: e. hall BCA-I building
- C₁-C₃: e. hall BCA-I building



ALL: 8 AM or 13 PM





Handouts

- Clean room (T1-T4)
 C, S and N: (clean room paper)
 - (normal paper)
 - Questions about the process flow

- C1-C3

Process flow slides

- S1-S2

Wafer page

- N1-N2





Evaluation

T, C, N: a single oral examination session in front of a jury (2 professors).

"Explain how you ensure that the rinsing of your samples is complete. Does this method work equally well for acids, bases and solvents?"

Notes taken on the handouts are considered in the mark (laboratory notebook)

S: a single 3-5 pages report

Final mark = oral (T, C, N) 75% + report (S) 25%

Unjustified absence: -2 points on final mark





Evaluation and reporting

- Session reporting rules:
 Evaluation:
 - Fixed and communicated by each session professor.

- Reports (max 15 pages)
- S3-S4: course L. Rufer

- - For each session: Reports and participation Unjustified absence: -2 points per 4h lab
- Final mark:

$$FM = \frac{4T_{1-4} + 2S_{1-2} + 3C_{1-3} + 2N_{1-2}}{11}$$





Reports

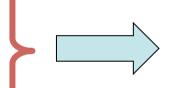
	Groups of	Preparation	Deadline
T, C	4	Read the documents	2 weeks after the final session
S1-S2	2	Read the documents	2 weeks after the final session
N	2	Read the documents, do the calculations	At the end of each session





Conclusion

- Four categories of labs in CIME-MINATEC:
 - Simulation
 - Technology
 - Characterization
 - Nanoworld



Complete
Micro-nanotech
process flow

- State-of-the-art tools and procedures
- One contact person assigned per lab type
- In case of problems, warn us in time!

